



#### 175°C N-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C
30V	$9.5$ m $\Omega$ @ V <sub>GS</sub> = 10V	55A
307	11.5mΩ @ V <sub>GS</sub> = 4.5V	50A

## **Description**

This new generation MOSFET has been designed to minimize the onstate resistance ( $R_{DS(ON)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## **Applications**

- Backlighting
- DC-DC Converters
- Power Management Functions

### **Features**

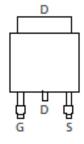
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switch (UIS) test in production
- Low On-Resistance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

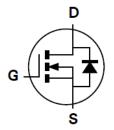
- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.33 grams (Approximate)



Top View



Pin Out Top View



**Equivalent Circuit** 

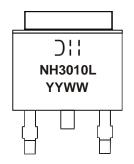
### Ordering Information (Note 4)

Part Number	Case	Packaging
DMNH3010LK3-13	TO252 (DPAK)	2500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

# Marking Information



Old = Manufacturer's Marking
NH3010L = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 15 = 2015)
WW = Week Code (01 to 53)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteris	Symbol	Value	Unit		
Drain-Source Voltage	$V_{DSS}$	30	V		
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Durin Compant (Note C) V	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	I <sub>D</sub>	55 40	А
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +100^{\circ}C$	I <sub>D</sub>	15 10.6	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	I <sub>DM</sub>	100	Α		
Avalanche Current (Note 7) L = 0.8mH			I <sub>AS</sub>	15	Α
Avalanche Energy (Note 7) L = 0.8mH			Eas	75	mJ

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$P_{D}$	2.0	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ heta JA}$	74	°C/W
Themai Resistance, Junction to Ambient (Note 3)	t<10s		31	°C/W
Total Power Dissipation (Note 6)		$P_D$	3.2	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ heta JA}$	47	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s		21	°C/W
Thermal Resistance, Junction to Case (Note 6)	$R_{ heta JC}$	2.5	°C/W	
Operating and Storage Temperature Range	$T_{J_i} T_{STG}$	-55 to +175	°C	

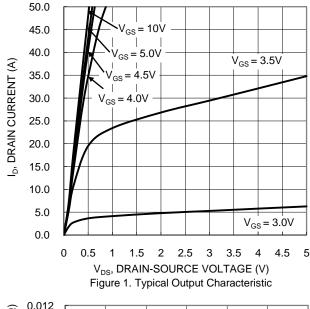
# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

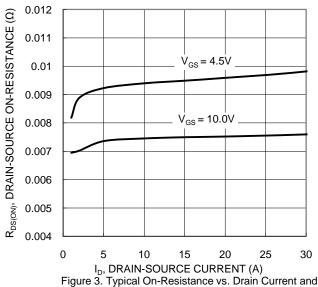
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.0	_	2.5	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance		_	8	9.5	mΩ	$V_{GS} = 10V, I_D = 18A$	
Static Dialit-Source Off-Nesistance	R <sub>DS(ON)</sub>	_	10	11.5	11122	$V_{GS} = 4.5V, I_D = 16A$	
Diode Forward Voltage	$V_{SD}$	_	0.75	1.0	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	$C_{iss}$	_	2075	_		V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Output Capacitance	Coss	_	190	_	pF		
Reverse Transfer Capacitance	Crss	_	138	_		1 – 1.01/11 12	
Gate Resistance	$R_g$	_	2.4	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	$Q_g$	_	16.1	_			
Total Gate Charge (V <sub>GS</sub> = 10V)	$Q_{g}$	_	37	_	nC	\\\\ 45\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	
Gate-Source Charge	$Q_{gs}$	_	6.1	_	iiC	$V_{DS} = 15V, I_{D} = 18A$	
Gate-Drain Charge	$Q_{gd}$	_	5.9	_			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	4.5	_			
Turn-On Rise Time	t <sub>R</sub>	_	19.6	_		$V_{DS} = 15V, V_{GS} = 10V,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	31	_	ns	$R_L = 0.83\Omega$ , $R_{GEN} = 3\Omega$	
Turn-Off Fall Time	t <sub>F</sub>	_	10.7	_			
Reverse Recovery Time	t <sub>RR</sub>	_	13.7	_	ns	1 454 41/41 5004/	
Reverse Recovery Charge	$Q_{RR}$	_	18.3	_	nC	I <sub>F</sub> =15A, di/dt=500A/μs	

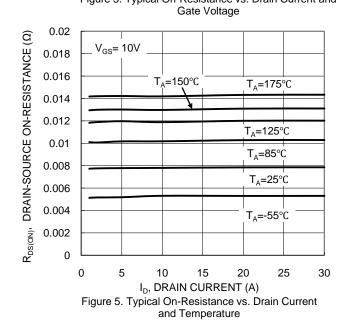
Notes:

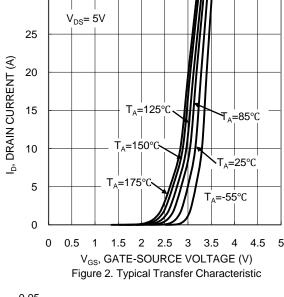
- 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
- 7.  $I_{AS}$  and  $E_{AS}$  ratings are based on low frequency and duty cycles to keep  $T_J = +25$ °C.
- Short duration pulse test used to minimize self-heating effect.
   Guaranteed by design. Not subject to product testing.



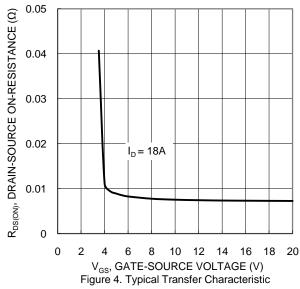








30



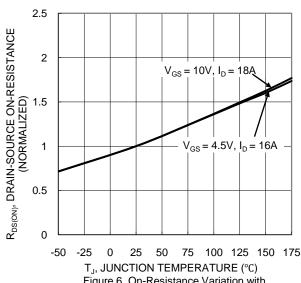


Figure 6. On-Resistance Variation with Temperature



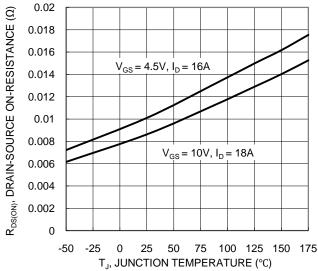
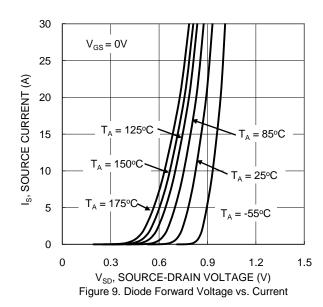
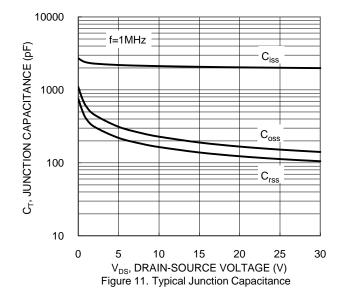


Figure 7. On-Resistance Variation with Temperature





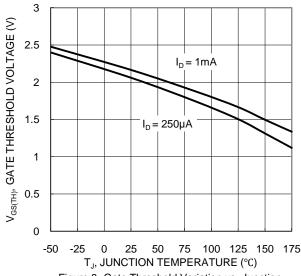
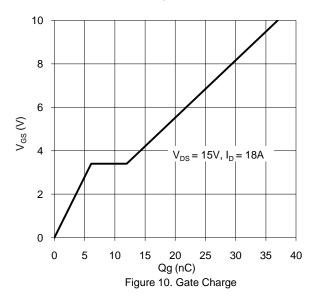
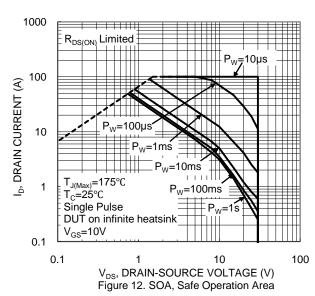


Figure 8. Gate Threshold Variation vs. Junction Temperature







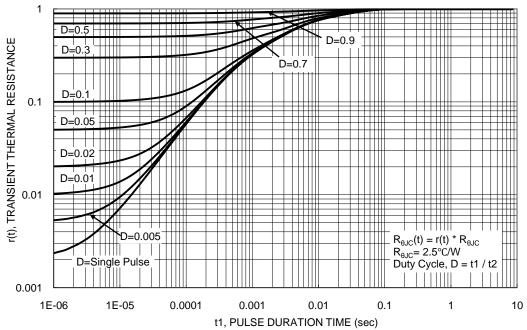
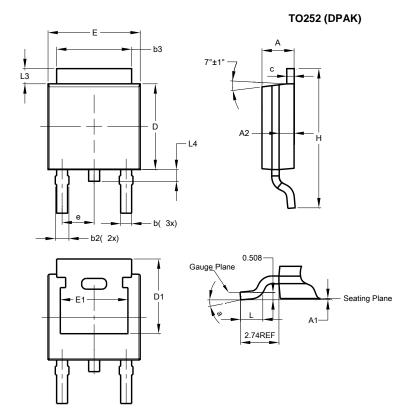


Figure 13. Transient Thermal Resistance



# **Package Outline Dimensions**

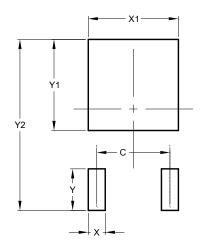
Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.



TO252 (DPAK)						
Dim	Min	Max	Тур			
Α	2.19	2.39	2.29			
<b>A</b> 1	0.00	0.13	0.08			
<b>A2</b>	0.97	1.17	1.07			
b	0.64	0.88	0.783			
b2	0.76	1.14	0.95			
b3	5.21	5.46	5.33			
C	0.45	0.58	0.531			
D	6.00	6.20	6.10			
D1	5.21	-	-			
е	-	-	2.286			
Е	6.45	6.70	6.58			
E1	4.32	-	-			
H	9.40	10.41	9.91			
٦	1.40	1.78	1.59			
L3	0.88	1.27	1.08			
L4	0.64	1.02	0.83			
а	0°	10°	-			
All Dimensions in mm						

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.



TO252 (DPAK)

Dimensions	Value (in mm)				
С	4.572				
Х	1.060				
X1	5.632				
Y	2.600				
Y1	5.700				
Y2	10 700				



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